

4Ω,400MHz Bandwidth, Dual-Channel SPDT Analog Switch with Negative Signaling Capability

FEATURES

- -3dB Bandwidth: 400MHz
- Supply Range: +2.5V to +5.5V
- Negative Signal Swing Capability:
 -2V to V₊
- Break-Before-Make Switching
- Fast ton, toff Times
- 1.8V Logic Control
- Extended Industrial Temperature Range: -40°C to +85°C
- Small Package Available in Green QFN-1.4x1.8-10L Package

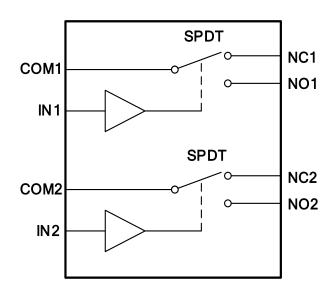
APPLICATIONS

- Wearable Devices
- Battery-Operated Equipment
- Signal Gating, Chopping, Modulation or Demodulation (Modem)
- Portable Computing
- Cell Phones

DESCRIPTION

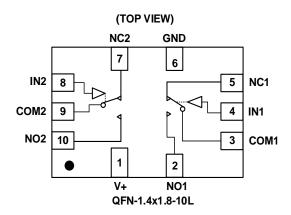
The RS2117 is a bidirectional, dual-channel single-pole double-throw (SPDT) analog switch that is designed to operate from 2.5V to 5.5V, and the switches can handle negative signal down to -2.0V. The device also offers a low ON-state resistance of 4Ω (typical), which is matched to within 1 Ω between channels. This device is available packaged in QFN-1.4x1.8-10L.

Functional Block Diagram





PIN CONFIGURATIONS



PIN DESCRIPTION

NAME	PIN	FUNCTION		
V+	1	Power Supply		
NO1, NO2	2,10	Normally-Open Terminal		
COM1, COM2	3,9	Common Terminal		
IN1, IN2	4,8	Digital Control Pin		
NC1, NC2	5,7	Normally-Closed Terminal		
GND	6	Ground		

NOTE: NOX, NCX and COMX terminals may be an input or output.

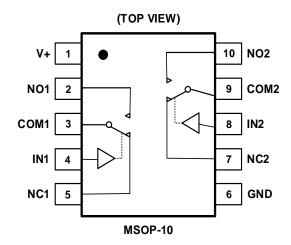
FUNCTION TABLE

LOGIC	NO	NC
0	OFF	ON
1	ON	OFF

NOTE: Switches shown for logic "0" input.



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ABSOLUTE MAXIMUM RATINGS (1)

V+, IN to GND0.3V to 6.0V
Analog Voltage Range (2)2.0 to (V+) + 0.3V
Digital Voltage Range (2)0.3 to (V+) + 0.3V
Continuous Current NO, NC, or COM ±100mA
Peak Current NO, NC, or COM ±150mA
Storage Temperature65°C to +150°C
Operating Temperature −40°C to +85°C
Junction Temperature+150°C
Package Thermal Resistance @ T _A = +25°C
QFN-1.4x1.8-10L120°C/W
Lead Temperature (Soldering, 10s)260°C
ESD Susceptibility
HBM2000V
MM200V

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3V beyond the supply rails should be current-limited to 10mA or less.



ESD SENSITIVITY CAUTION

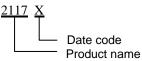
ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING (1)	PACKAGE OPTION
RS2117	RS2117YUTQK10	-40°C ~+85°C	QFN-1.4x1.8-10L	2117X	Tape and Reel,4000
RS2117	RS2117YN	-40°C ~+85°C	MSOP-10	RS2117	Tape and Reel,3000

(1) NOTE: X = Date Code

MARKING INFORMATION





ELECTRICAL CHARACTERISTICS

V+ = 5.0 V, $T_A = -40 ^{\circ}\text{C}$ to $85 ^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	CONDITIONS	V+	TA	MIN	TYP	MAX	UNITS	
ANALOG SWITCH									
Analag Cignal Danga	., ., .,	2.5V ≤V+≤3.5V		FULL	-2.0		V+	V	
Analog Signal Range	Vno, Vnc, Vcom	3.5V ≤V+≤ 5.5V			(V+)-5.5		V+		
			5V	+25°C		4	7	Ω	
On-Resistance	Ron	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_{+},$ $I_{COM} = -10 \text{mA}, \text{ Switch ON},$	οv	FULL			7.5	Ω	
On-ivesistance	NON	See Figure 1	3.3V	+25°C		6	9	Ω	
			0.0 V	FULL			9.5	Ω	
			5V	+25°C		0.15	0.5	Ω	
On-Resistance Match	Δ Ron	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_{+},$	30	FULL			0.6	Ω	
Between Channels	ΔΚΟΝ	I _{COM} = -10mA, Switch ON, See Figure 1	3.3V	+25°C		0.25	0.85	Ω	
			3.34	FULL			1.0	Ω	
	RFLAT(ON)	$0 \leqslant (V_{NO} \text{ or } V_{NC}) \leqslant V+,$ I_{COM} = -10mA, Switch ON, See Figure 1	5V	+25°C		1	2	Ω	
On Desistance Flateres				FULL			2.5	Ω	
On-Resistance Flatness			0.01/	+25°C		3	5	Ω	
			3.3V	FULL			5.4	Ω	
NC, NO OFF Leakage Current	INC(OFF), INO(OFF)	V _{NO} or V _{NC} = 0.3V, V+/2 V _{COM} = V+/2, 0.3V See Figure 2	2.5V to 5.5V	FULL			1	μΑ	
NC, NO, COM ON Leakage Current	Inc(on), Ino(on), Icom(on)	V _{NO} or V _{NC} = 0.3V, Open V _{COM} = Open, 0.3V See Figure 3	2.5V to 5.5V	FULL			1	μΑ	
DIGITAL CONTROL INP	UTS ⁽¹⁾								
In a set I limb \ / a lt = m a			5V	FULL	1.5			V	
Input High Voltage	Vinh		3.3V	FULL	1.3			V	
Input Low Valtage	VINL		5V	FULL			0.5	V	
Input Low Voltage			3.3V	FULL			0.4	V	
Input Leakage Current	lin	Vin = Vio or 0	2.5V to 5.5V	FULL			1	μΑ	

⁽¹⁾ All unused digital inputs of the device must be held at Vio or GND to ensure proper device operation.

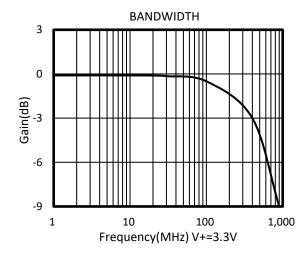


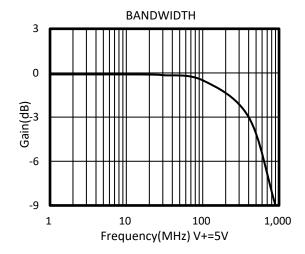
ELECTRICAL CHARACTERISTICS (continued) V+ = 5.0 V, TEMP= -40°C to 85°C (unless otherwise noted))

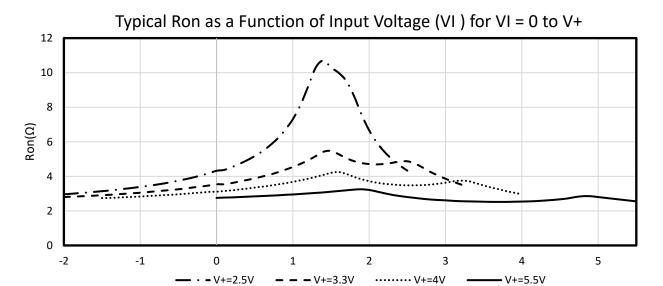
PARAMETER	SYMBOL	CONDITIONS		V+	TEMP	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTER	RISTICS								
Turna On Time	4	$V_{COM} = V+, R_L = 300\Omega, C_L = 35pF,$		5V	. 0500		15		
Turn-On Time	ton	See Figure 5	•	3.3V	+25°C		25		ns
Turns Off Times	4	$V_{COM} = V+, R_L = 300\Omega, C_L = 35pF,$		5V	0500		10		
Turn-Off Time	toff	See Figure 5	•	3.3V	+25°C		15		ns
Break-Before-Make		V _{NO1} = V _{NC1} = V _{NO2} = V _{NC2} = V+/2.		5V	250		5		
Time Delay	tввм	$R_L = 300\Omega$, $C_L = 35pF$,	See Figure 6	3.3V	+25°C		10		ns
Ohanna Iniaatian		V_G =GND, R_G =0 Ω , C_L =1.0nF, See Figure 10		5V	+25°C		15		
Charge Injection	Q			3.3V	+25°C		10		pC
	_	$R_L = 50\Omega$, Switch OFF, $f = 1MHz$ See Figure 8 $f = 10MH$	f = 1MHz		+25°C		-70		dB
Off Isolation	Oiso		f = 10MHz		+25°C		-50		dB
-3dB Bandwidth	BW	Switch ON, R _L = 50Ω S	See Figure 7		+25°C		400		MHz
Channel-to-Channel	V	Signal=0dBm, R _L =	f = 1MHz		+25°C		-72		dB
Crosstalk	XTALK	50Ω , C _L = 5pF, See Figure 9	f = 10MHz		+25°C		-52		dB
NC, NO OFF Capacitance	CNC(OFF), CNO(OFF)	V _{NC} or V _{NO} =V+/2 or GND, Switch OFF See Figure 4			+25°C		10		pF
NC, NO, COM ON Capacitance	CNC(ON), CNO(ON), CCOM(ON)	V _{NC} or V _{NO} =V+/2 or GND, Switch ON See Figure 4			+25°C		25		pF
POWER REQUIREMENT	тѕ								
Power Supply Range	V+				FULL	2.5		5.5	٧
Power Supply Current	I+	V _{IN} = GND or V ₊		5.5V	FULL			1	μΑ



TYPICAL CHARACTERISTICS









Parameter Measurement Information

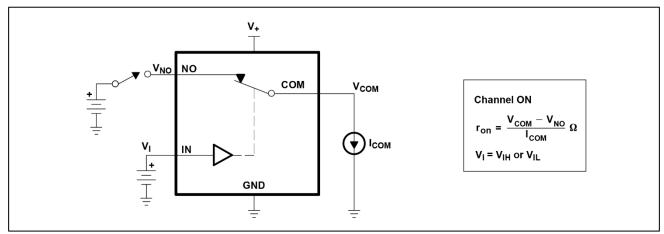


Figure 1.ON-State Resistance (ron)

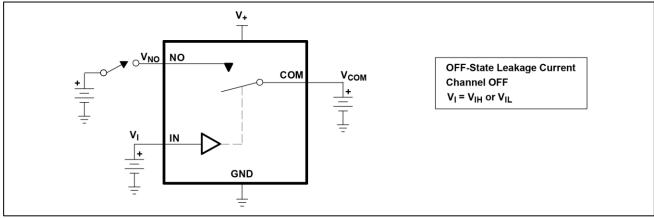


Figure 2.OFF-State Leakage Current (ICOM(OFF), INO(OFF))

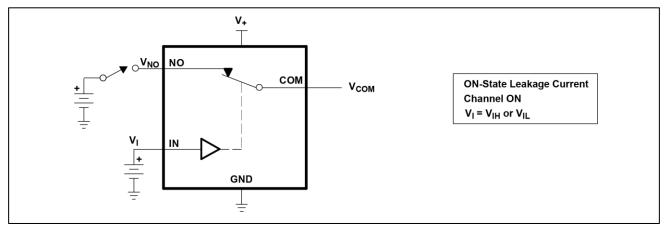


Figure 3.ON-State Leakage Current (ICOM(ON), INO(ON))

8



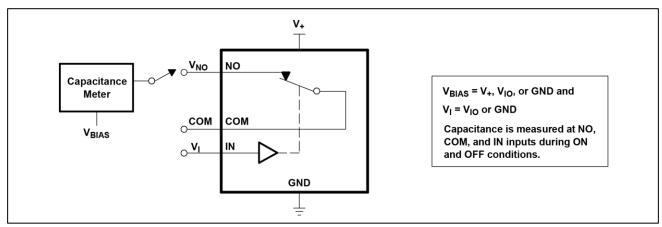


Figure 4. Capacitance (CI, CCOM(OFF), CCOM(ON), CNO(OFF), CNO(ON))

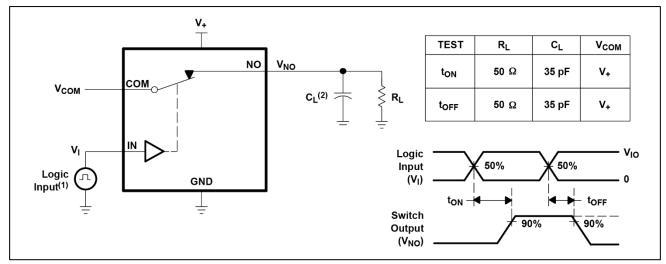


Figure 5.Turn-On (ton) and Turn-Off Time (toff)

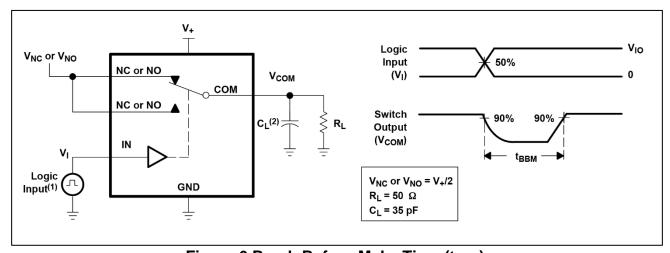


Figure 6.Break-Before-Make Time (tbbm)

9



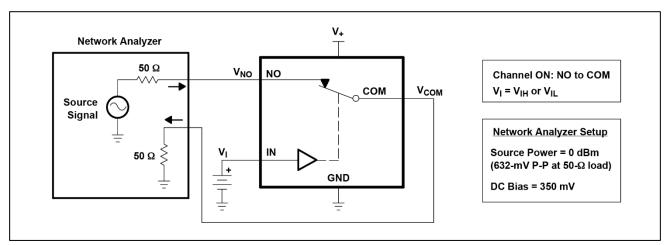


Figure 7. Bandwidth (BW)

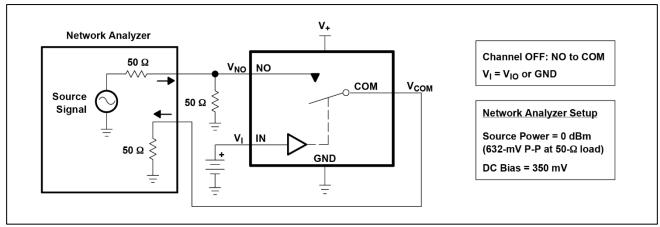


Figure 8.OFF Isolation (O_{ISO})

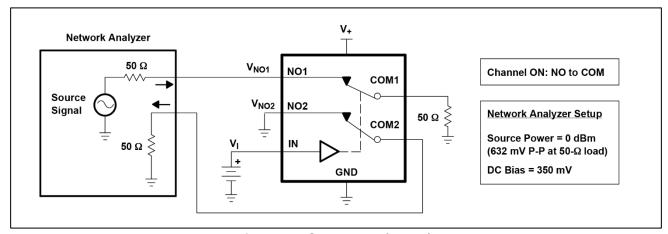


Figure 9. Crosstalk (XTALK)

10



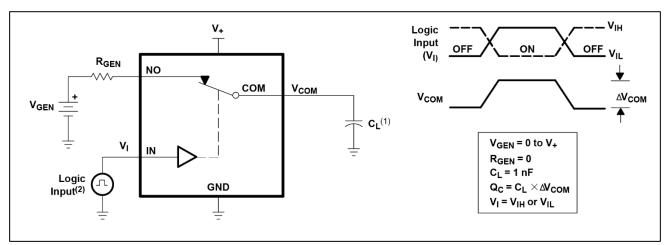


Figure 10. Charge Injection (Qc)

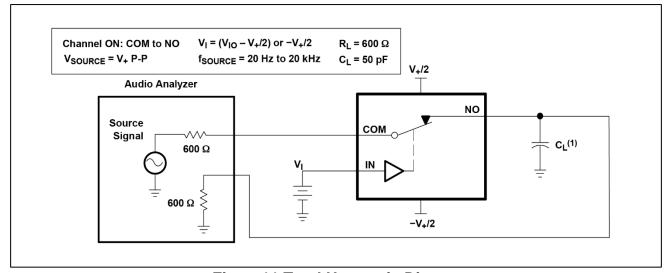


Figure11.Total Harmonic Distort



TYPICAL APPLICATION

Analog signals that range over the entire supply voltage V_{CC} to GND can be passed with very little change in ON-state resistance. The switches are bidirectional, so the NO, NC, and COM pins can be used as either inputs or outputs. Pull the digitally controlled input select pin IN to V_{CC} or GND to avoid unwanted switch states that could result if the logic control pin is left floating.

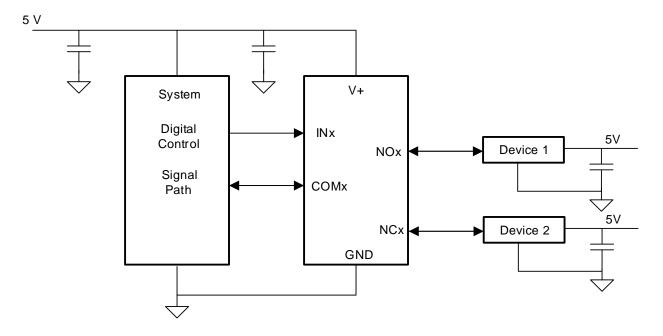
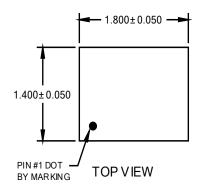
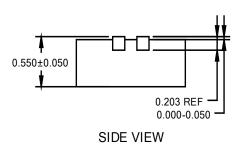


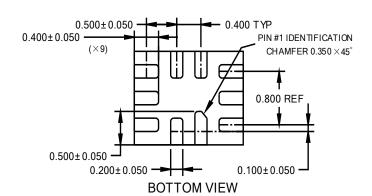
Figure 12. Typical Application Schematic

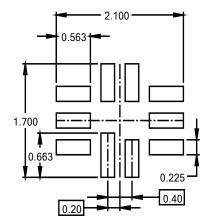


PACKAGE OUTLINE DIMENSIONS QFN-1.4x1.8-10L





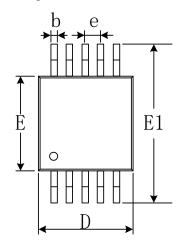


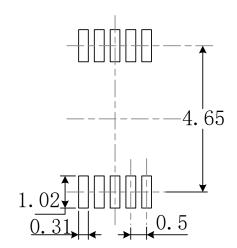


RECOMMENDED LAND PATTERN

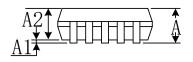


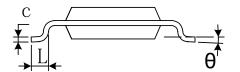
MSOP-10





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions I	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
А	0.820	1.100	0.032	0.043		
A1	0.020	0.150	0.001	0.006		
A2	0.750	0.950	0.030	0.037		
b	0.180	0.280	0.007	0.011		
С	0.090	0.230	0.004	0.009		
D	2.900	3.100	0.114	0.122		
е	0.50(BSC)		0.020(BSC)			
Е	2.900	3.100	0.114	0.122		
E1	4.750	5.050	0.187	0.199		
L	0.400	0.800	0.016	0.031		
θ	0°	6°	0°	6°		